

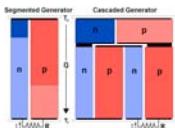
Use of the Compatibility Factor to Select Materials for Efficient Segmented and Cascaded Thermoelectric Generators

G. Jeff Snyder, Thierry Caillat

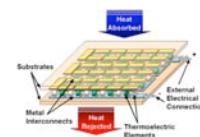
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Funded by NASA
DARPA, ONR



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Segmented Design

$$\eta \approx \frac{\Delta T}{T_h} \frac{\sqrt{1+zT} - 1}{\sqrt{1+zT} + 1}$$

Use Largest Temperature Difference

- Maximize Carnot $\Delta T/T_h$
- 1200K to 300K for RTG

Interface Temperature Design

- Where zT cross
 z is only *materials* parameter considered
- Adjusted with relative lengths l
 - $\Delta T \propto l/\kappa$

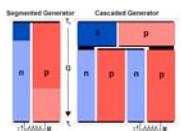
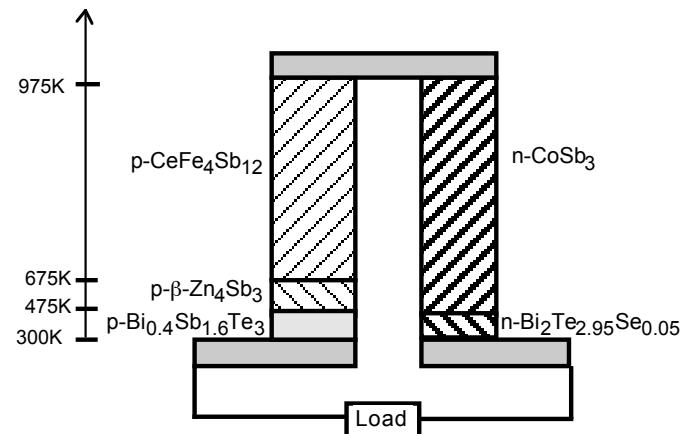
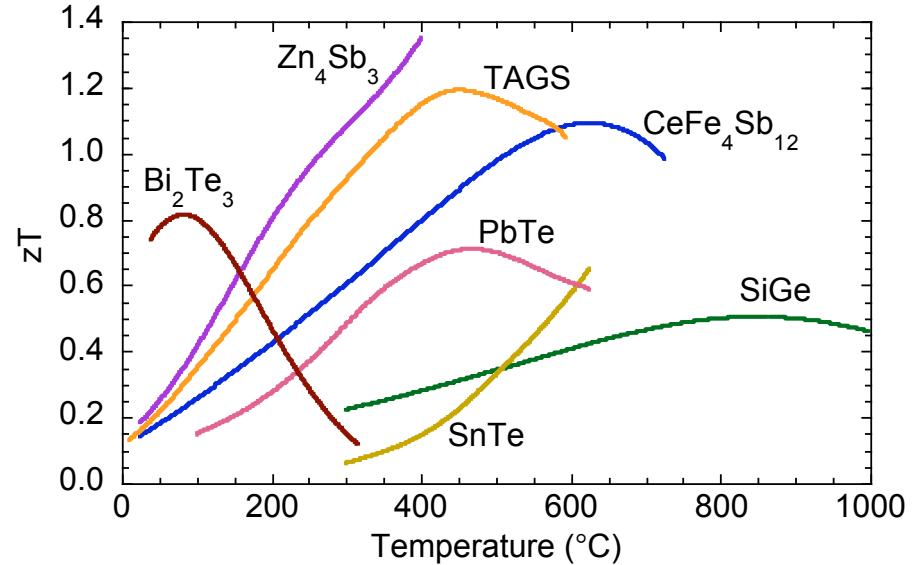
High Temperature Region

> 700°C Skutterudites

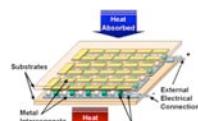
> 525°C TAGS

SiGe alloys have highest zT

Should be included in segmentation ?



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Compatibility

Efficiency depends on reduced current, u

Just like the Power curve

- Current draw gives IR drop
- $\eta = P/Q_{in}$

η maximum at specific reduced current (u)

$$u = I/Q_c$$

Best u at compatibility factor s

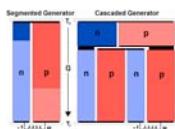
$$s = \frac{\sqrt{1+zT} - 1}{\alpha T}$$

SiGe Requires different u compared with other TE materials

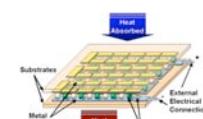
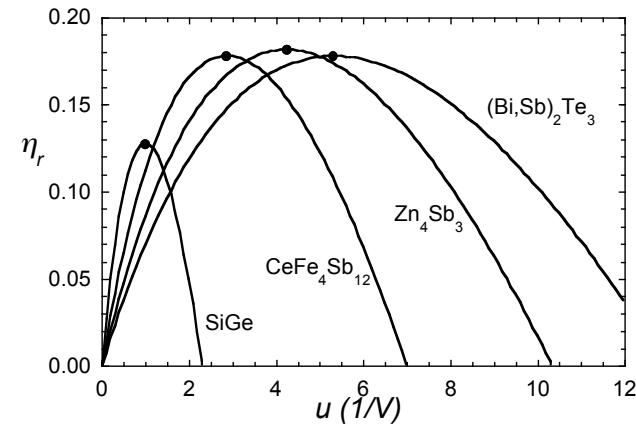
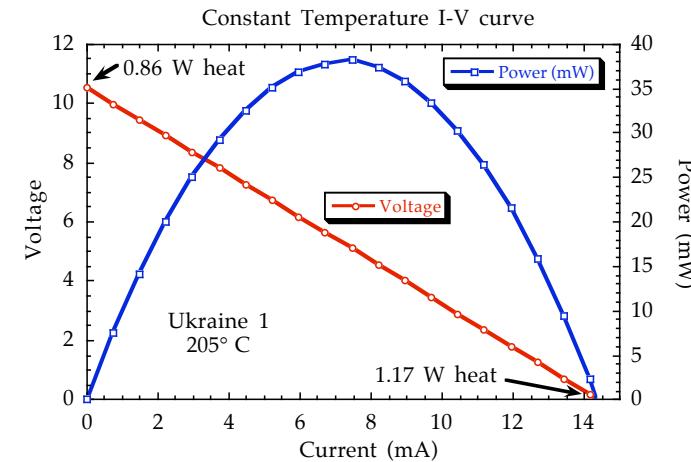
- Different $s \Rightarrow$ not compatible

Goal

- High zT
 - Determines efficiency at $u = s$
- Compatible s
 - Within about a factor of 2



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Improved Segmented TAGS

TAGS has high zT - stable to 525°C

10.45% efficiency

n-PbTe stable to 600°C

525°C to 600°C p-type segment needed

p-PbTe has highest zT (before skutterudites)

But not compatible ($s_{\text{PbTe}} < 2 s_{\text{TAGS}}$)

10.33% efficiency decrease

p-SnTe has low zT , and some compatibility

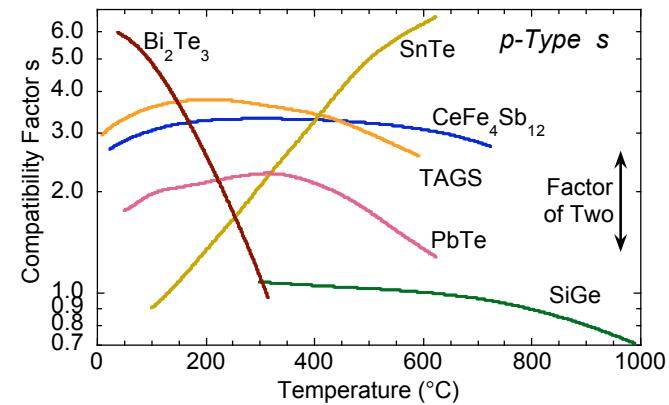
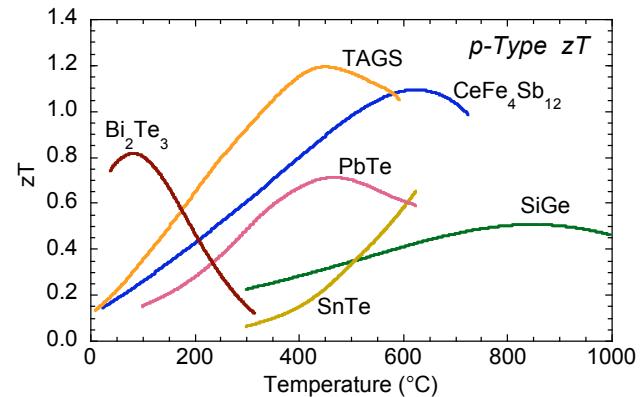
$s_{\text{SnTe}} \geq 2 s_{\text{TAGS}}$

11.09% small efficiency increase

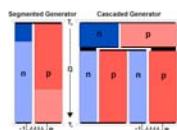
p-Skutterudite has high zT , and *compatibility*

11.87% large efficiency increase

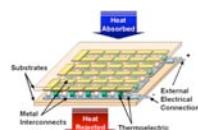
13.56% for 700°C hot side



Material	Efficiency (%)	T_c (C)	$T_{\text{Interface}}$ (C)	T_h (C)	$u(T_c)$ (V $^{-1}$)
p-TAGS	10.45	100	-	525	2.97
p-TAGS/PbTe	10.33	100	525	600	2.33
p-TAGS/SnTe	11.09	100	525	600	2.84
p-TAGS/CeFe ₄ Sb ₁₂	11.87	100	525	600	2.94
p-TAGS/CeFe ₄ Sb ₁₂	13.56	100	525	700	2.88



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High Temperature High Efficiency

Segmented n-type can go to 1000°C

13.76% Efficiency with n-SiGe

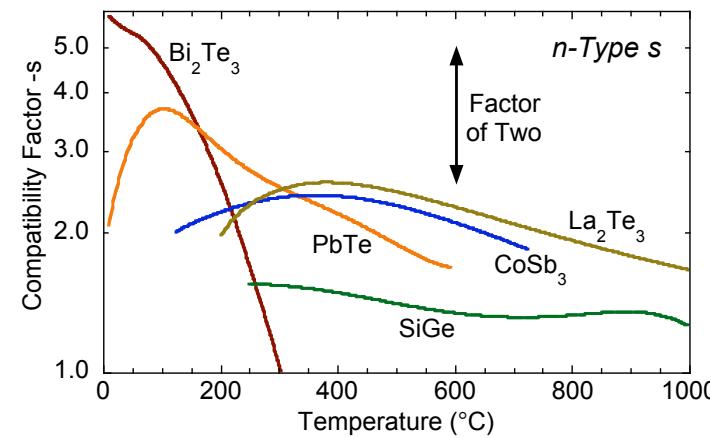
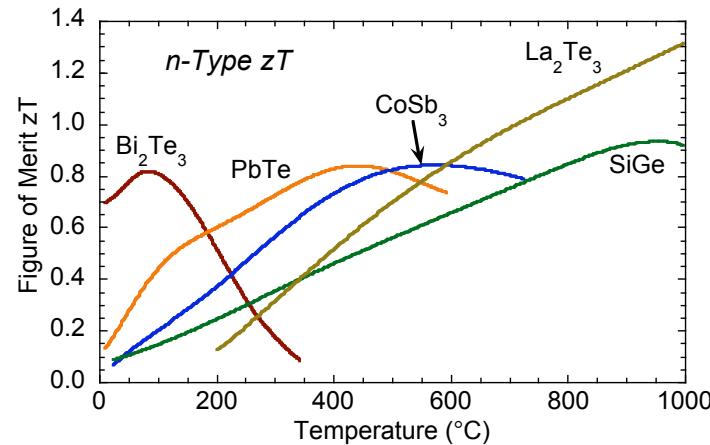
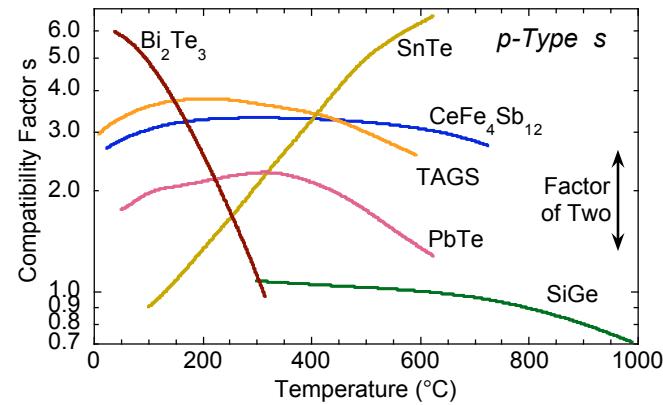
Some compatibility

15.56% Efficiency with La₂Te₃

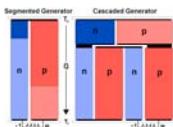
Good compatibility, high zT

Problem: no compatible p-type

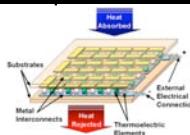
p-SiGe *lowers* efficiency



Material	Efficiency (%)	T_c (C)	T_{Int} (C)	T_h (C)	$u(T_d)$ (V $^{-1}$)
n-PbTe	9.87	100		600	-2.00
n-PbTe/SiGe	13.76	100	600	1000	-1.46
n-PbTe/La ₂ Te ₃	15.56	100	600	1000	-1.80
n-SiGe	5.44	600		1000	-1.29



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p-Type Material Needed

Must have high temperature p-Type

To utilize high n-type efficiency

Must have high s

Otherwise will decrease efficiency

$$s \approx z/2\alpha$$

Must have appreciable zT (0.5)

But *not* particularly high α

No large band gap semiconductors

SiGe

No small polaron conductors

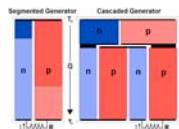
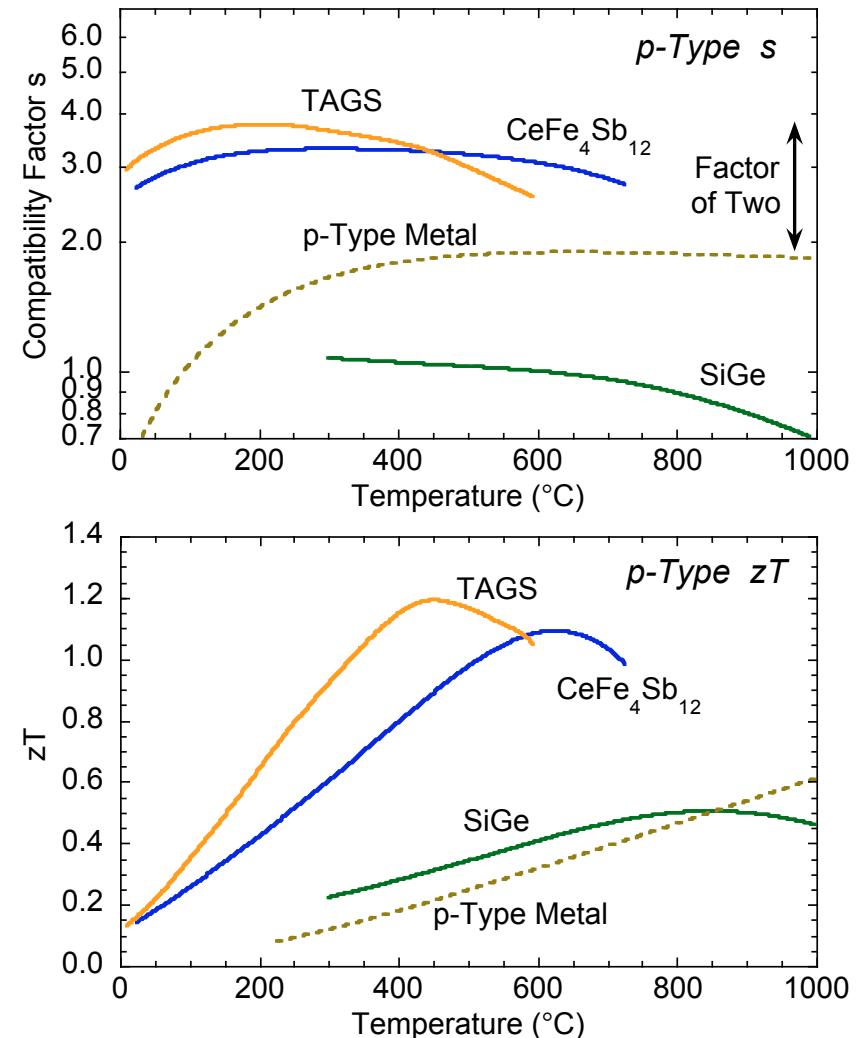
Boron Carbides

Require p-type Metal

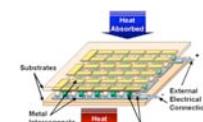
$$\kappa \approx \kappa_e = LT/\rho \text{ (Wiedemann Franz)}$$

With good thermopower

$$\alpha > 100 \mu\text{V/K} \text{ at } 1000\text{K}$$

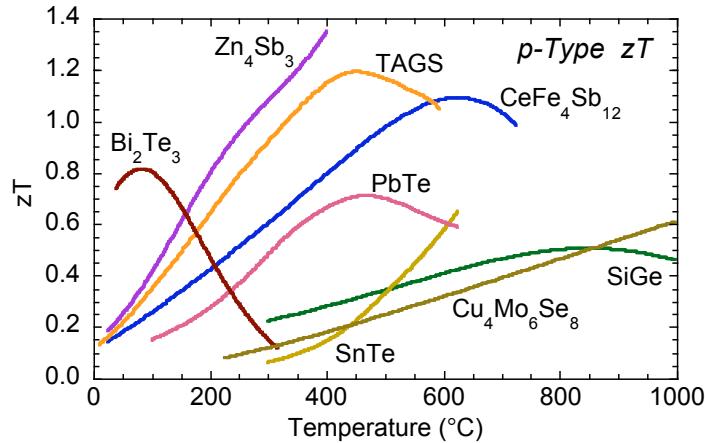


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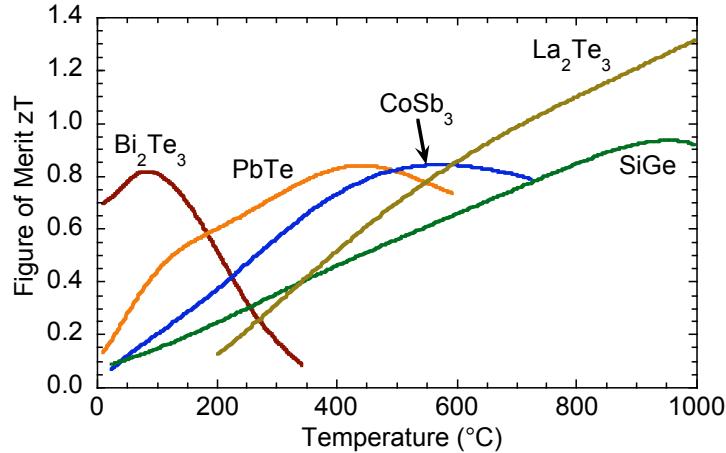
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Fully Segmented Generator



P-Element

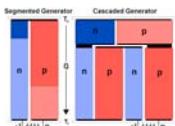
$\text{Cu}_4\text{Mo}_6\text{Se}_8$	(to 1000° C)
$\text{CeFe}_4\text{Sb}_{12}$	(to 700° C)
TAGS	(to 525° C)
Zn_4Sb_3	(to 400° C)
$(\text{Bi},\text{Sb})_2\text{Te}_3$	(25° C to 170° C)



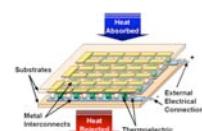
N-Element

La_2Te_3	(to 1000° C)
CoSb_3	(to 600° C)
PbTe	(to 480° C)
Bi_2Te_3	(25° C to 190° C)

18.1 % Generator Efficiency (25°C to 1000° C)



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Progress Status of Skutterudite-Based Segmented Thermoelectric Technology Development

2004 DOE High Efficiency Thermoelectric Workshop

T. Caillat, J. Sakamoto, L. Lara, A. Jewell, A. Kisor

Jet Propulsion Laboratory/California Institute of Technology

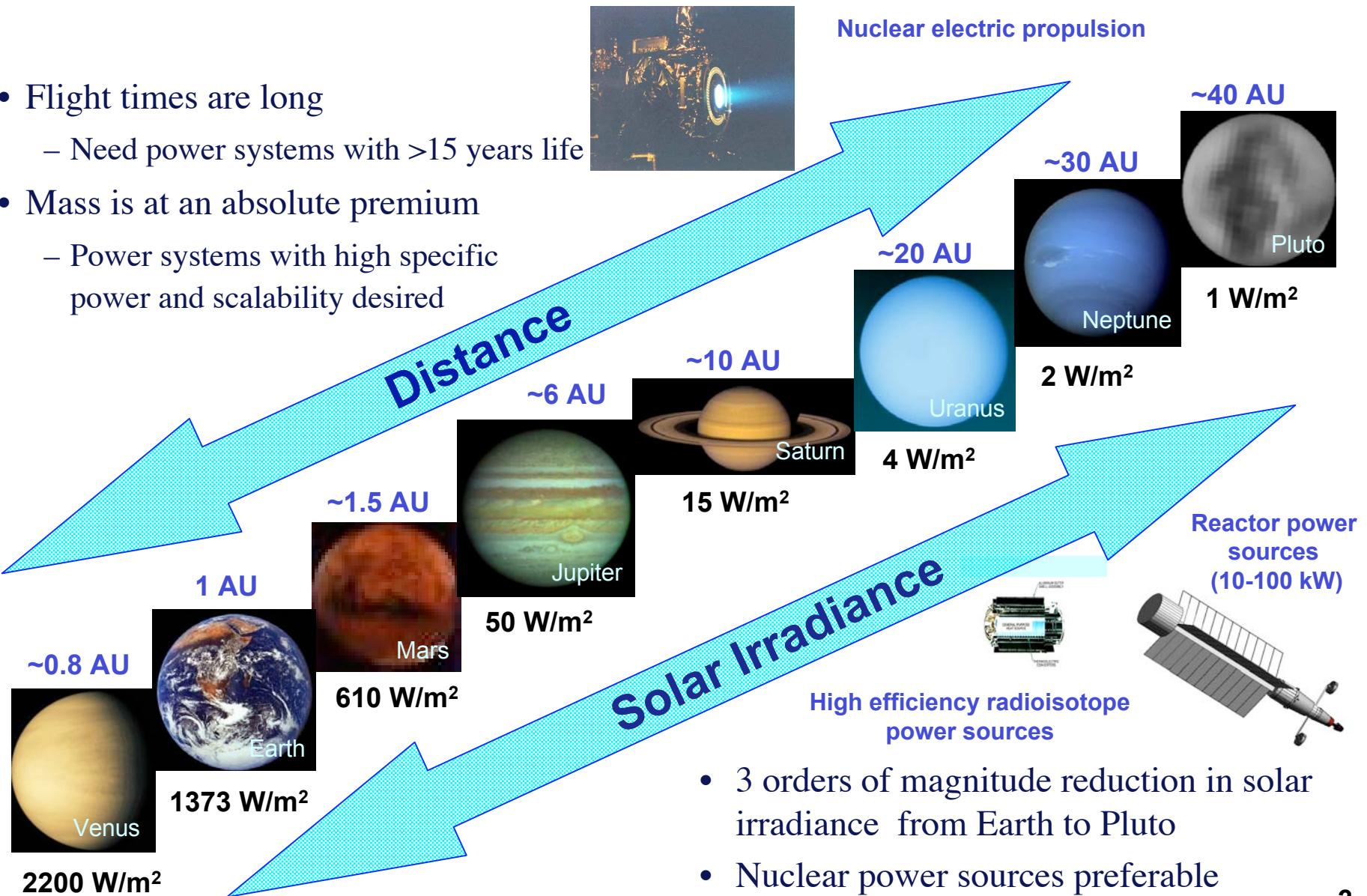
Acknowledgements:

Prof. M. El-Genk (University of New Mexico)
NASA (Project Prometheus), ONR & DARPA



Power Technology

- Flight times are long
 - Need power systems with >15 years life
- Mass is at an absolute premium
 - Power systems with high specific power and scalability desired



- 3 orders of magnitude reduction in solar irradiance from Earth to Pluto
- Nuclear power sources preferable



Advanced Radioisotope Power Systems (APRS) for NASA missions

- Overall objective:

Develop low mass, high efficiency, low-cost Advanced Radioisotope Power System with double the Specific Power and Efficiency over state-of-the-art radioisotope thermoelectric generators (RTGs)



Segmented Thermoelectric Technology (STE)

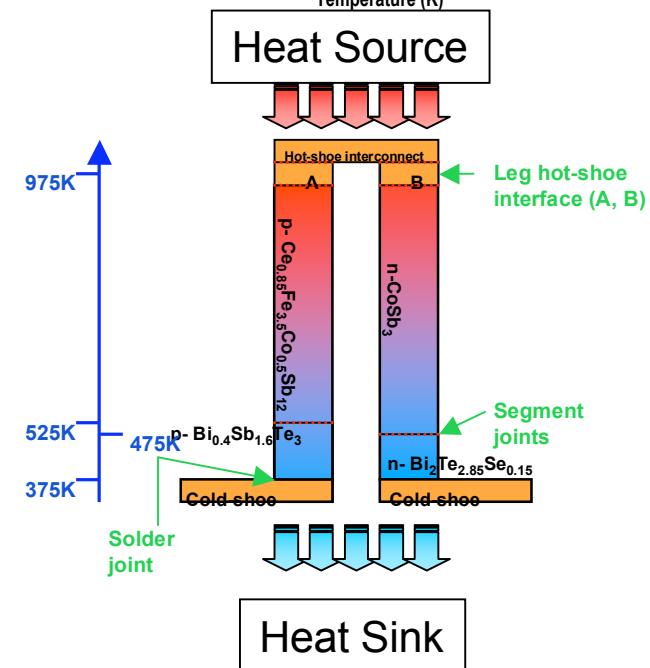
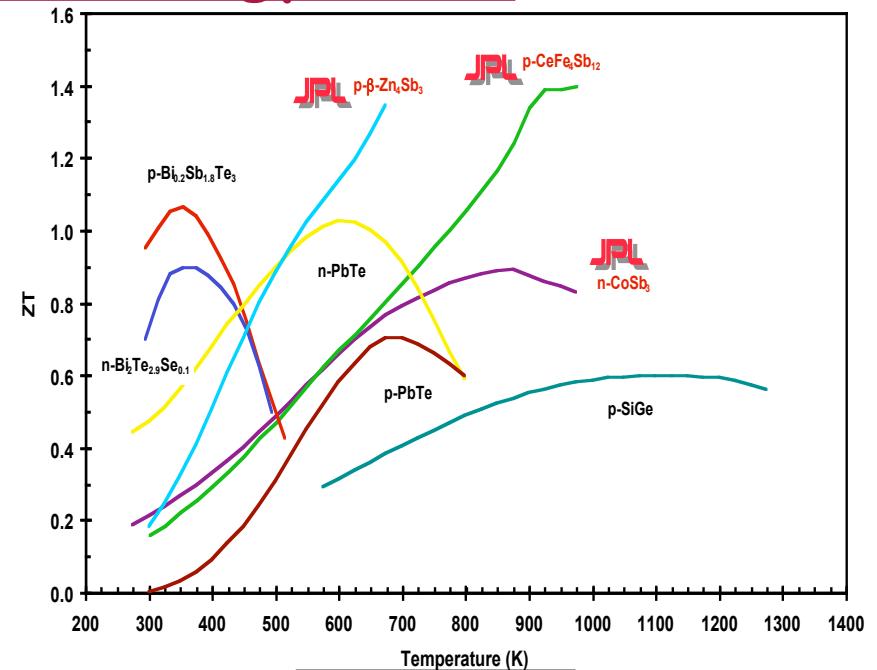
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- **New high ZT materials**
 - Development initiated in 1991 and supported by ONR and DARPA (Skutterudites and Zn_4Sb_3)
 - Substantial increase in efficiency over state-of-the-art

- **Segmented unicouples**
 - Large ΔT , high ZT \rightarrow high efficiency
 - Using a combination of state-of-the-art TE materials (Bi_2Te_3 -based materials) and new, high ZT materials developed at JPL
 - Skutterudites : $CeFe_4Sb_{12}$ and $CoSb_3$
 - Zn_4Sb_3
 - Current new materials operation limited to $\sim 975K$
 - Higher average ZT values
 - ➔ Higher material conversion efficiency
 - ➔ Up to 15 % for a 300-975K temperature gradient

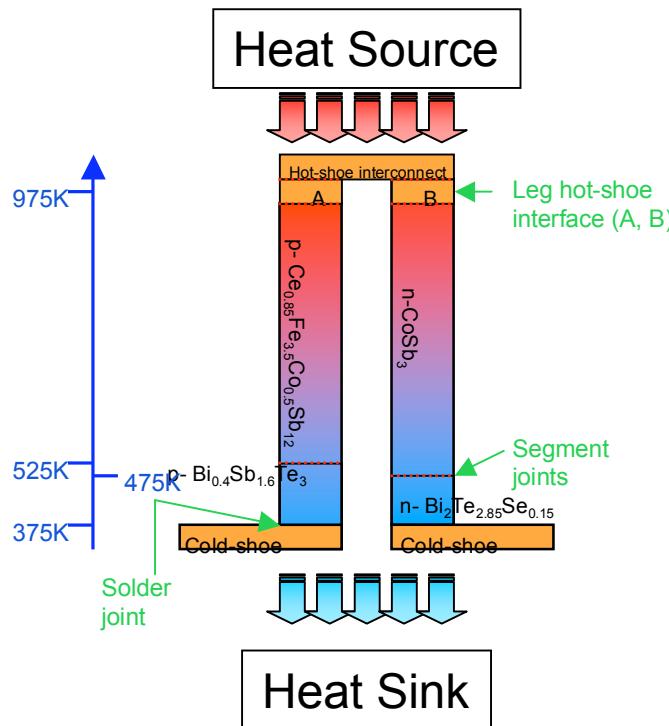
Efficiency

$$\eta = \frac{T_H - T_C}{T_H} \frac{\sqrt{1+ZT}-1}{\sqrt{1+ZT} + \frac{T_C}{T_H}}$$





Key Technology Challenges



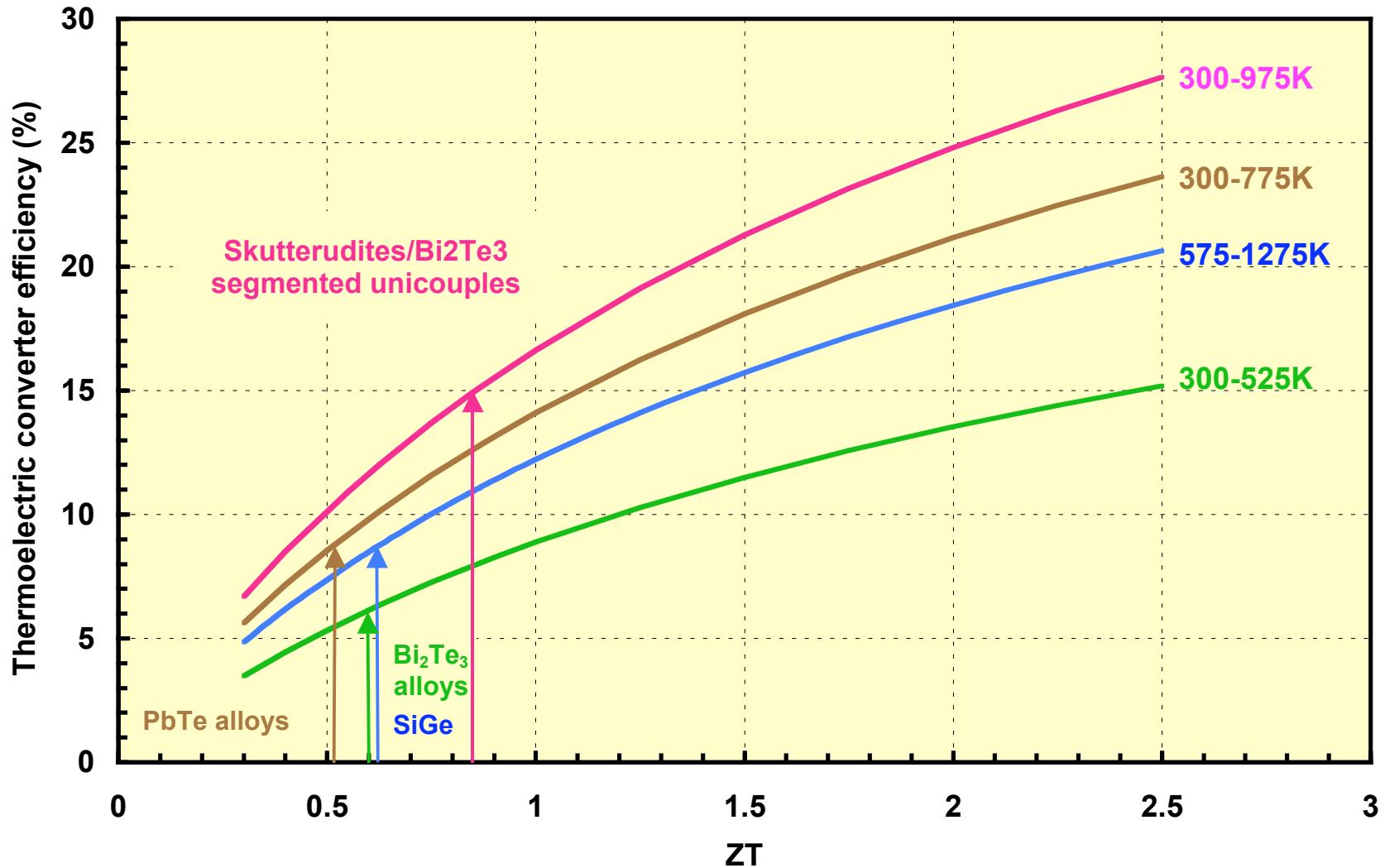
Key technology challenges

- TE materials processing and segmented leg fabrication
- Low electrical contact resistance between segments and between segments and cold- and hot-shoes
- Unicouple mechanical integrity
- Lifetime
 - Sublimation control
 - Stable thermoelectric properties
 - Life time prediction model
- Demonstrate unicouple performance
 - Testing and modeling



Converter efficiency : state-of-the-art vs. segmented thermoelectric technology

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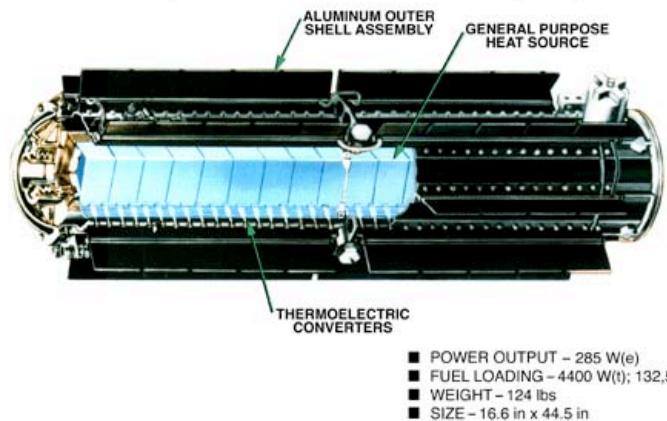
A 2x increase in efficiency over SOA thermoelectrics has been demonstrated for the STE technology



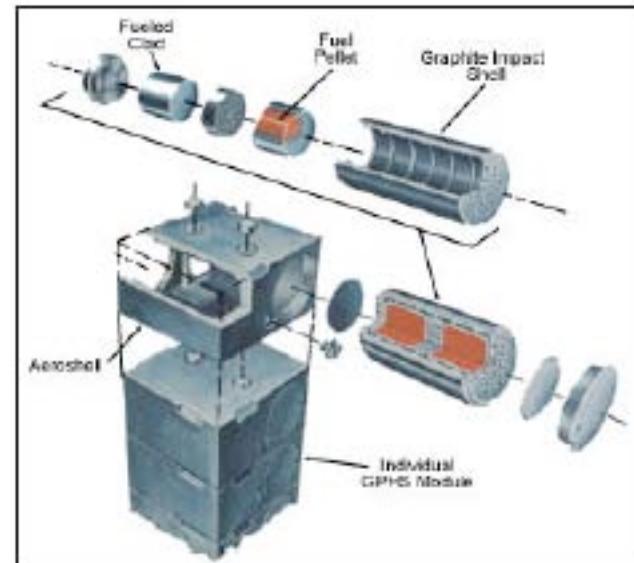
General Purpose Heat Source RTG



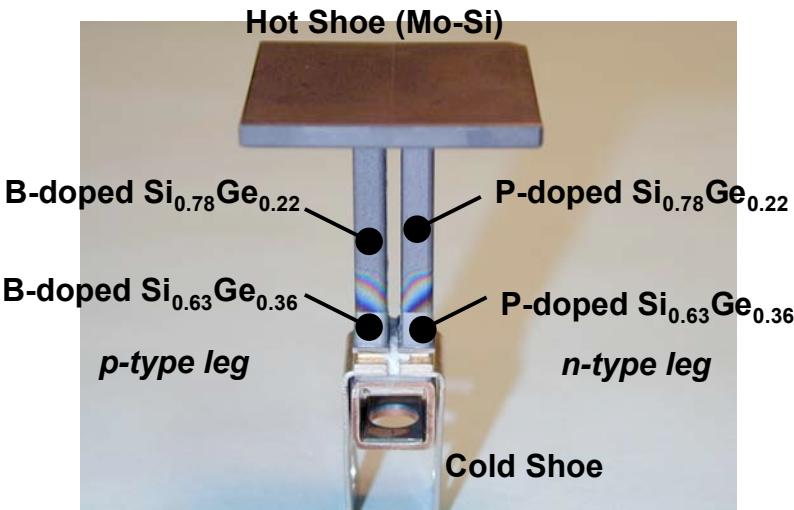
General Purpose Heat Source (GPHS) Radioisotope Thermoelectric Generator (RTG)



The three Radioisotope Thermoelectric Generators (RTGs) provide electrical power for Cassini's instruments and computers. They are being provided by the U.S. Department of Energy.



General Purpose Heat Source Module



GPHS SiGe unicouple

GPHS-RTG Performance Data

Power output-We	290 beginning of life 250 end of life
Operational life - hrs	40,000 after launch
Weight-kg	55.5
Output voltage	28
Dimensions	42.2 diameter 114 long
Hot junction temperature-K	1270
Cold junction temperature-K	566
Fuel	PuO ₂
Thermoelectric material	SiGe
Numbers of unicouples	572
Mass of Pu-238-g	7,561



STE-ARPS

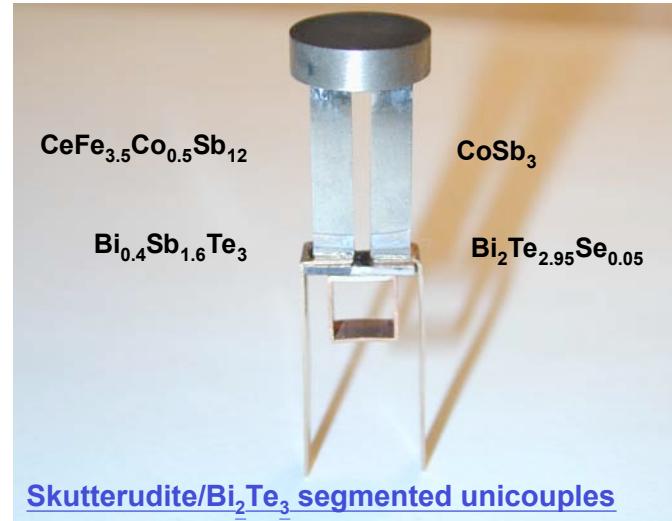
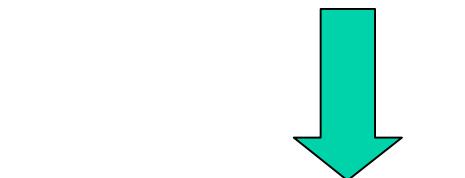
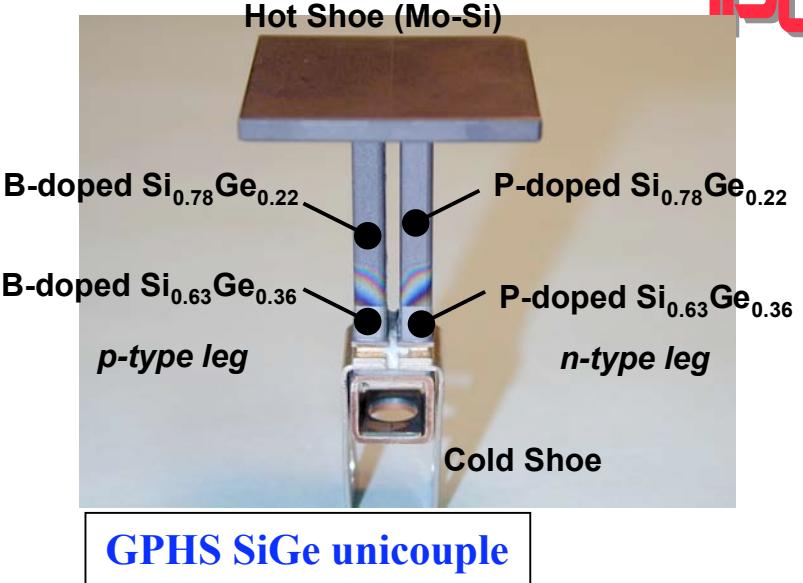
IPL

• STE-ARPS

- Would use advanced materials segmented legs
 - 700 to 100°C operation
 - Current GPHS-RTG unicouple design would be mostly conserved
 - Modifications required to radiator fins to accommodate for lower rejection temperature
 - Shorter housing
- New segmented unicouples could “replace” unicouples almost “one for one”

• Advantages of thermoelectrics

- Flight proven, long life demonstrated
- Solid state energy conversion -> reliability, no vibration, no moving parts
- Scalable
- No single point failure
- Significant system heritage





Projected STE 100W class ARPS specifications vs. SOA

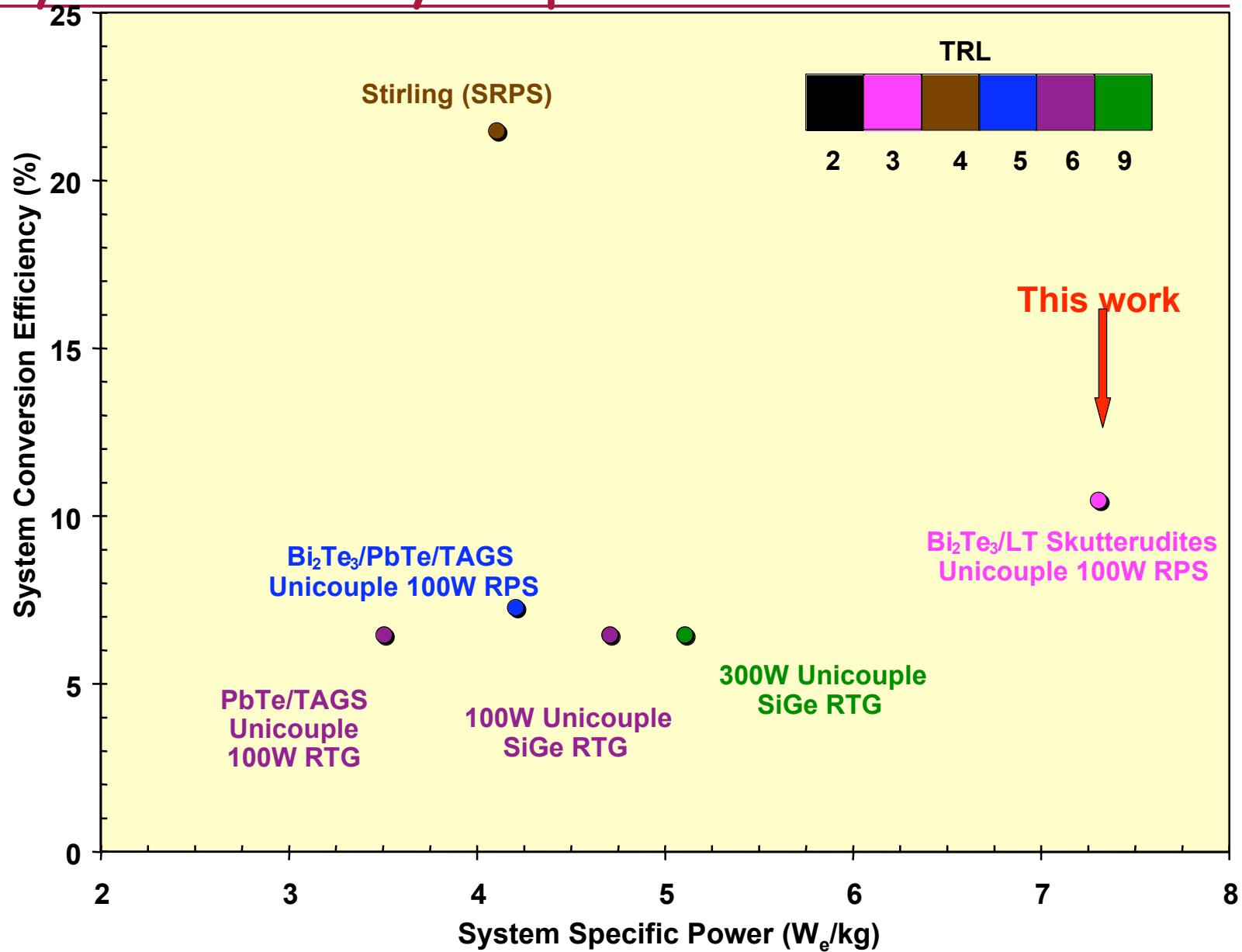


Item/Converter	SiGe-RTG	PbTe/TAGS MMRTG	Low T STE (LSTE)	High Temperature TE (HSTE)
Hot side temperature (K)	1273	823	975	1200
Cold side temperature (K)	573	453	375	375
Converter efficiency (%)	7.2	7.6	12.5	14.7
System efficiency (%)*	6.5	6.4	11.18	13.3
Thermal power (BOM)(W _{th})	2000	2000	1250	1000
Thermal efficiency (%)	85		85	85
Electrical power (BOM) (W _e)	107	110	118.8	113.0
Number of modules	8	8	5	4
Total PuO₂ mass (kg)	5.02	5.02	3.138	2.51
Total system mass estimate (kg)	23.24	38.1	16.3	13.1
- GPHs mass (kg)	11.54	12.83	7.215	5.77
- Housing (Kg)	3.1	4.2	1.90	1.55
- Radiator fins (kg)	0.45	3.32	1.7	1.36
- Converter (kg)	5.65	10	3.9	3.12
- Other structure (kg)	2.5	5.5	1.6	1.28
Specific power estimate (W_e/kg)	4.6	2.88	7.28	8.64
Unicouples				
	<p>Hot Shoe (Mo-93) B-doped Si_{1-x}Ge_x P-doped Si_{1-x}Ge_x p-type leg n-type leg Cold Shoe</p>	<p>N-Leg P-Leg Fe Cold Cap PbTe TAGS PbSbTe Fe Cup NiNiTe Cold Shoe</p>	<p>Heat Source 975K 525K 475K 375K p-Bi_{0.5}Sb_{0.5}Te₂ n-Bi₂Te_{2.5}Se_{0.15} Cold shoe Heat Sink</p>	<p>Heat Source 1275K 975K 525K 475K 375K p-Bi_{0.5}Sb_{0.5}Te₂ n-Bi₂To_{3.5}Se_{0.15} Cold shoe Heat Sink p- , n-type high temperature materials under development</p>

* 90% of converter efficiency

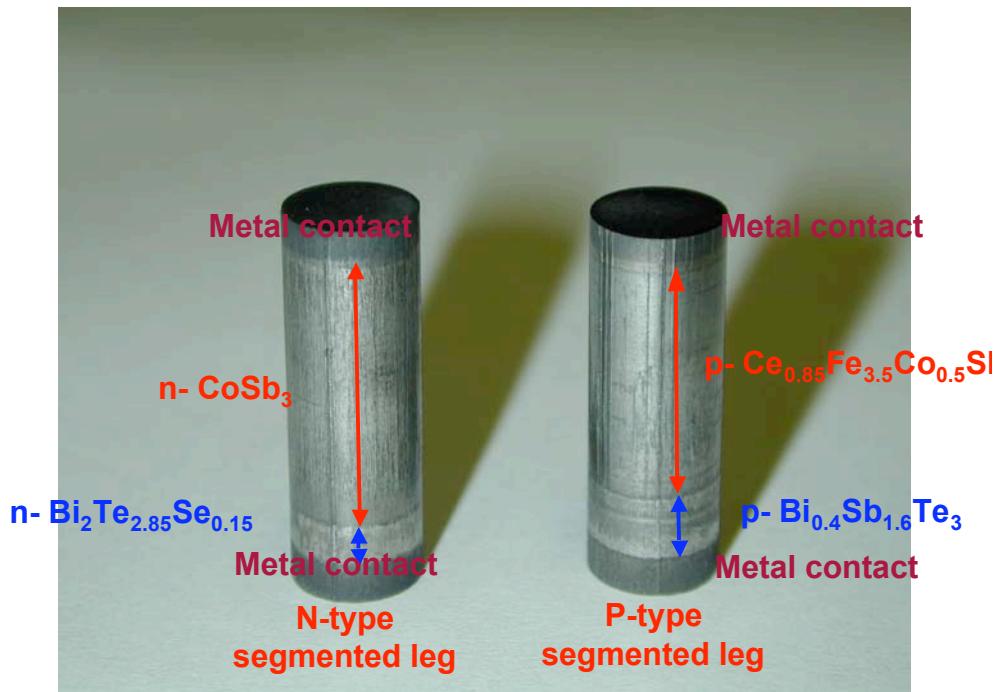


System Efficiency & Specific Power: STE vs. SOA



Unicouples legs

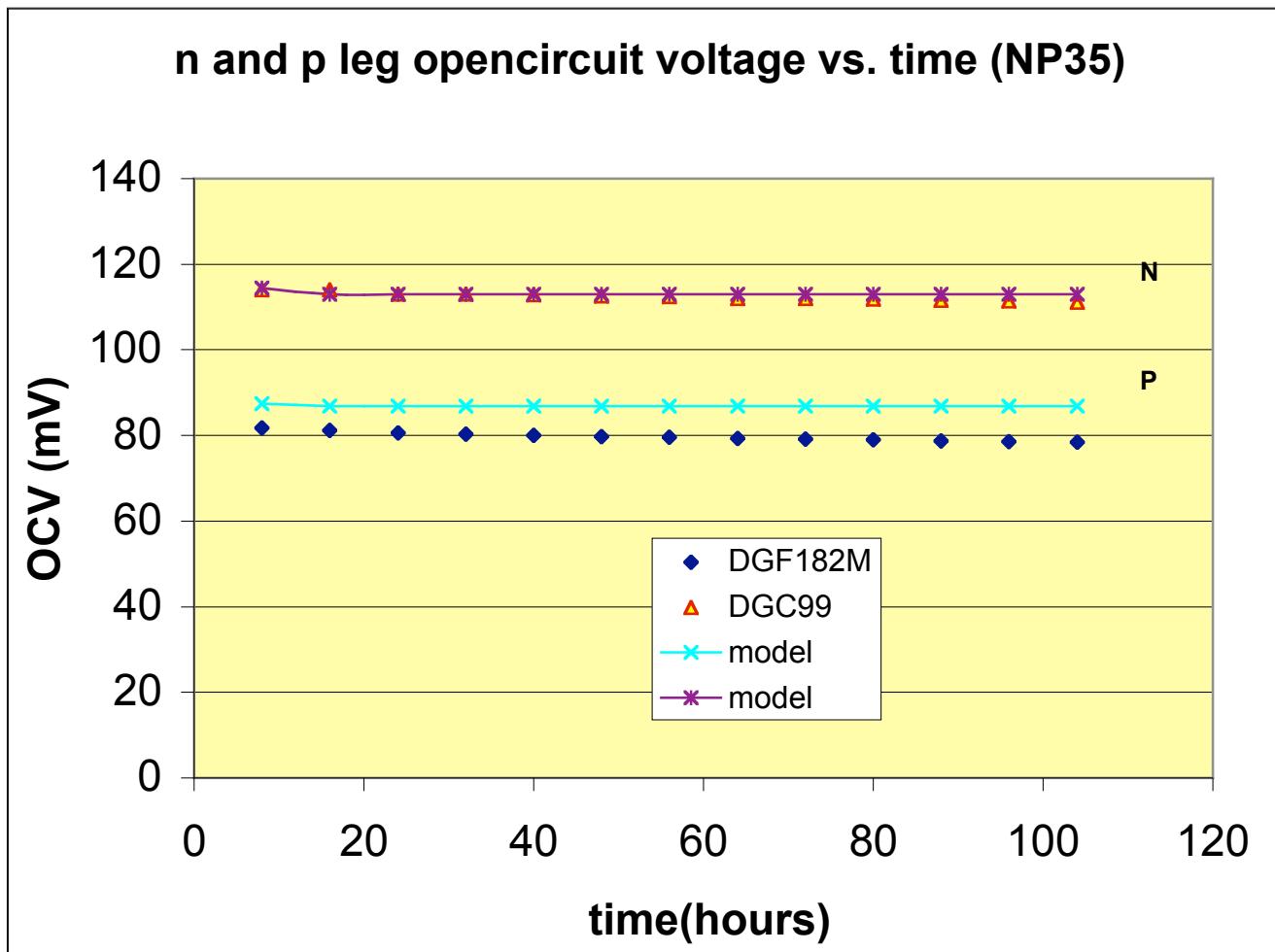
- Developed uniaxial hot-pressing technique for legs fabrication
 - Powdered materials stacked on the top of each other
 - Temperature optimized → density close to theoretical value
 - In graphite dies and under argon atmosphere
 - With metallic diffusion barriers between the TE materials
 - Metallic contacts at hot- and cold-side
 - Low electrical resistance bonds ($<5\mu\Omega\text{cm}^2$) achieved → negligible impact on overall unicouple performance





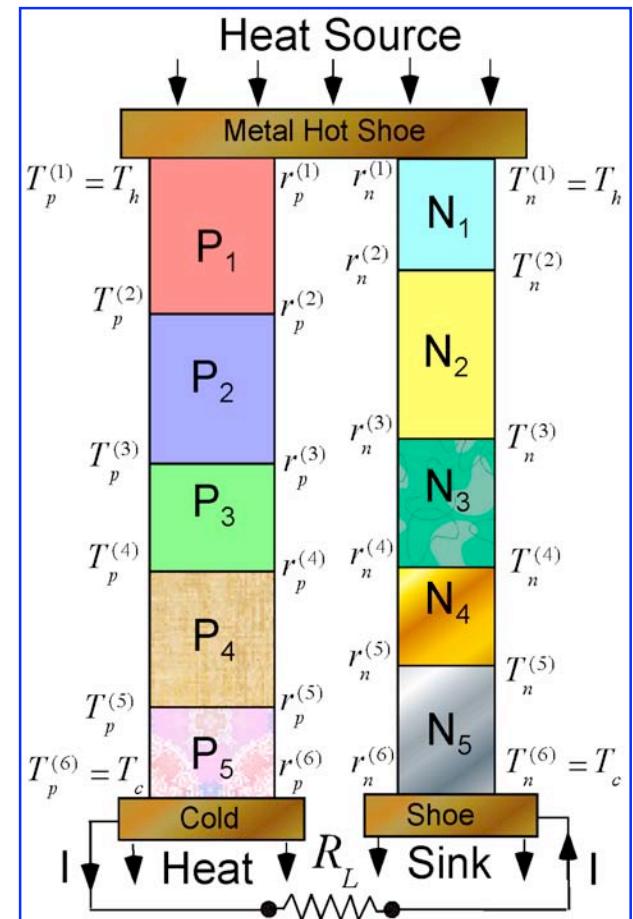
Unicouple legs - In-gradient testing

- N- and p-type in gradient (975K-350K) testing of n- and p-skutterudite legs confirm model performance prediction and show little voltage decrease after ~ 100 hours of testing



1-D Analytical Model of Segmented Thermoelectric Unicouples

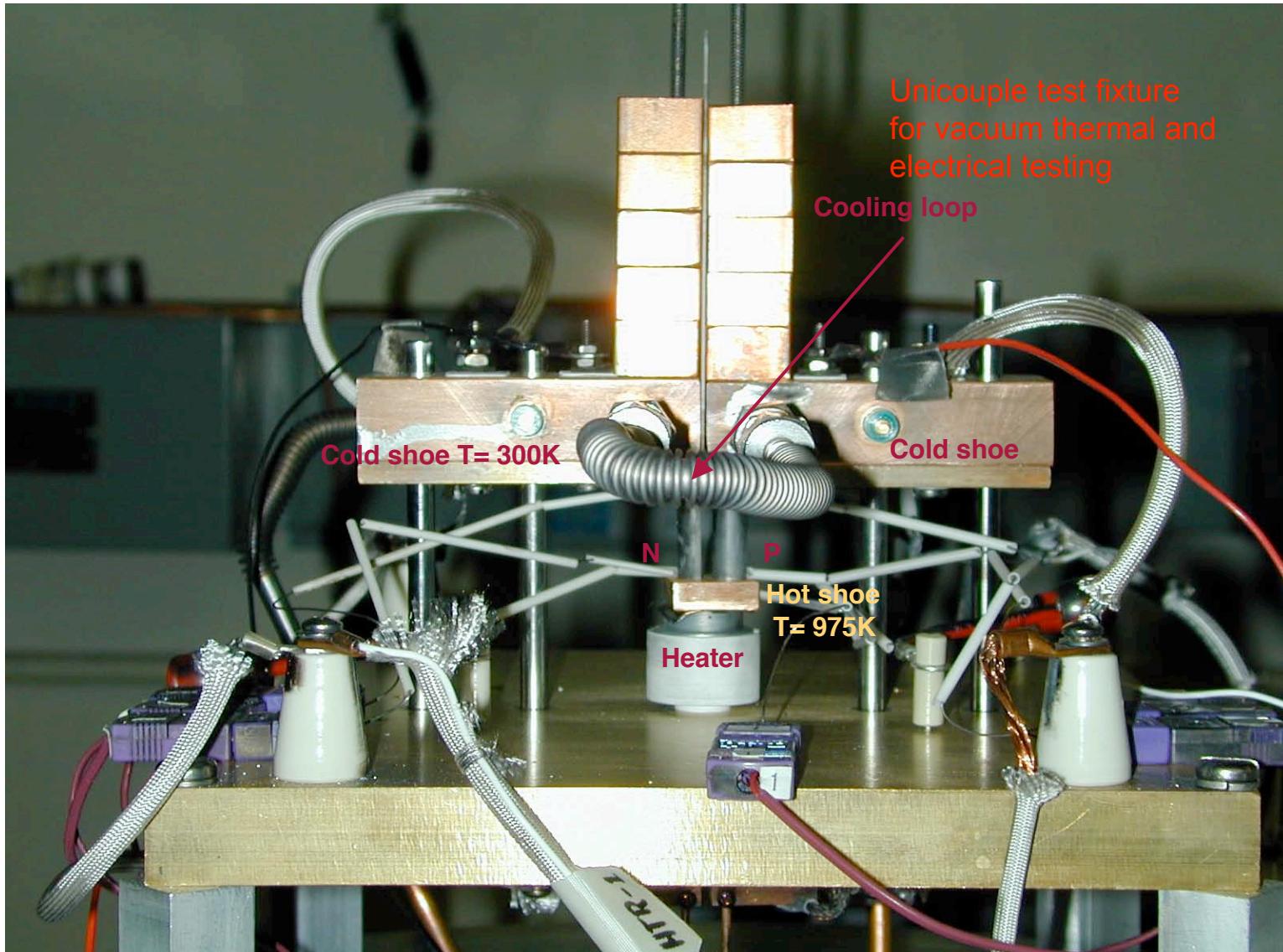
- One-dimensional analytical model of STEs, with up to 5 segments per leg, is coupled to a *genetic algorithm* for maximizing either electrical power or efficiency
- Input:
 - TE materials properties
 - Total length and composition of n- and p-legs
 - Cross sectional area of the p-leg (or the n-leg)
 - Hot and cold shoe temperatures
 - Total contact resistance per leg
- Output
 - Number of needed segments in n- and p-legs
 - Interface temperatures between various segments
 - Lengths of various segments in n- and p-legs
 - Cross sectional area of n-leg and p-legs
 - Electrical power and conversion efficiency curves
 - Operation I-V characteristics





Unicouple thermal and electrical testing

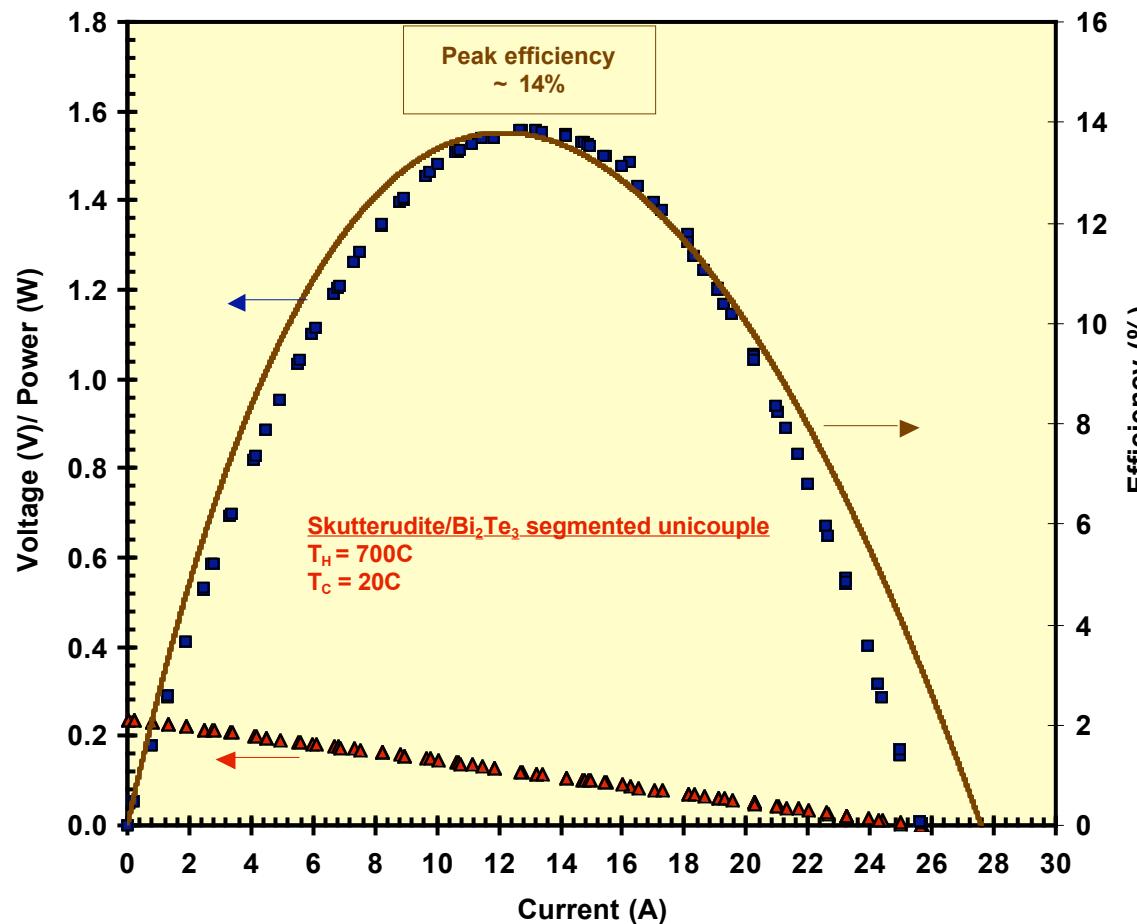
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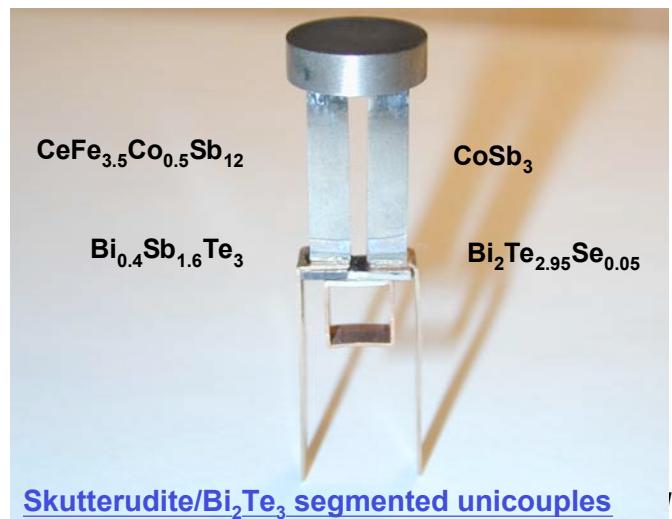
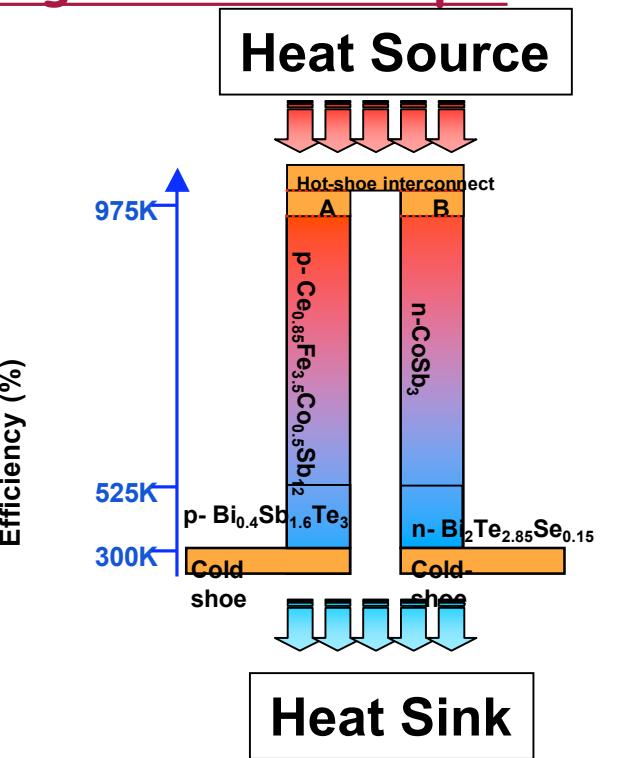


Thermal and electrical testing - Segmented unicouple

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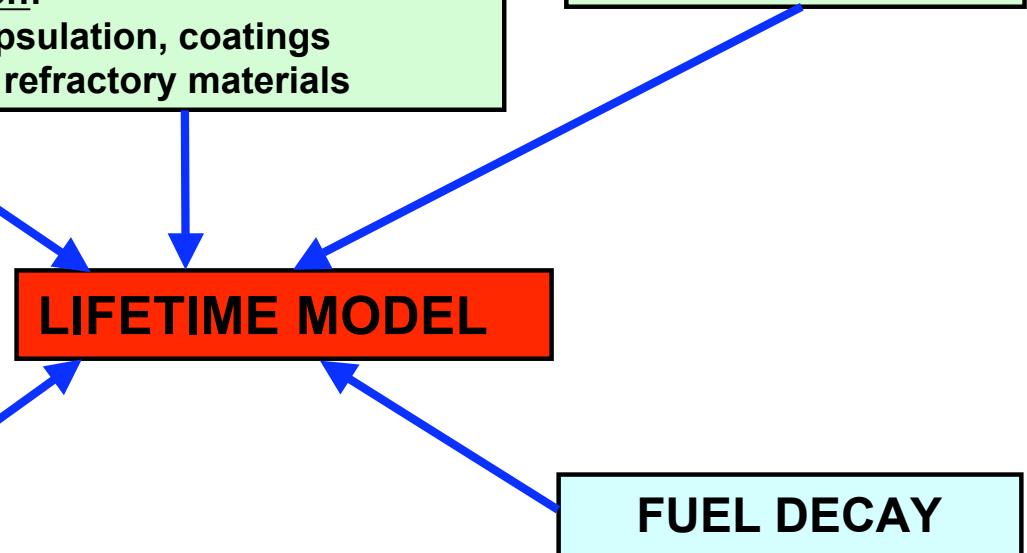
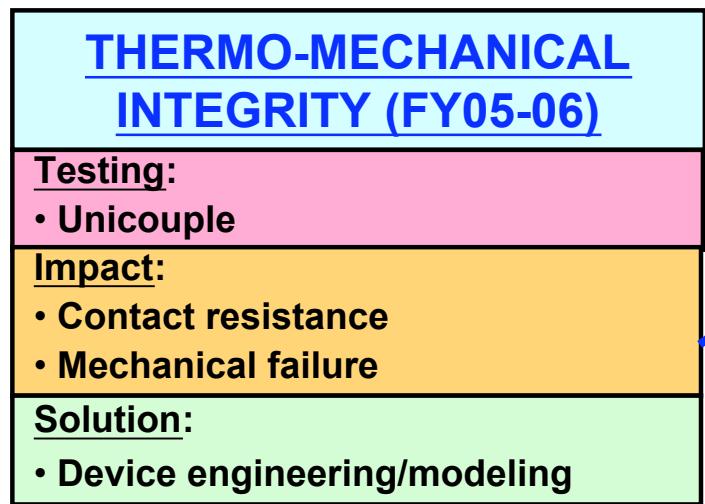
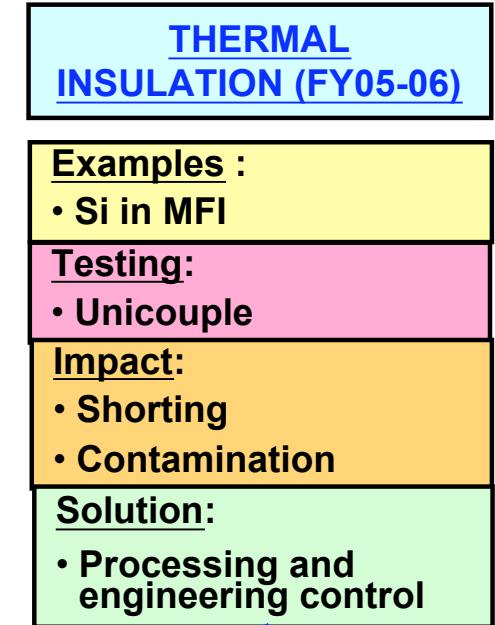
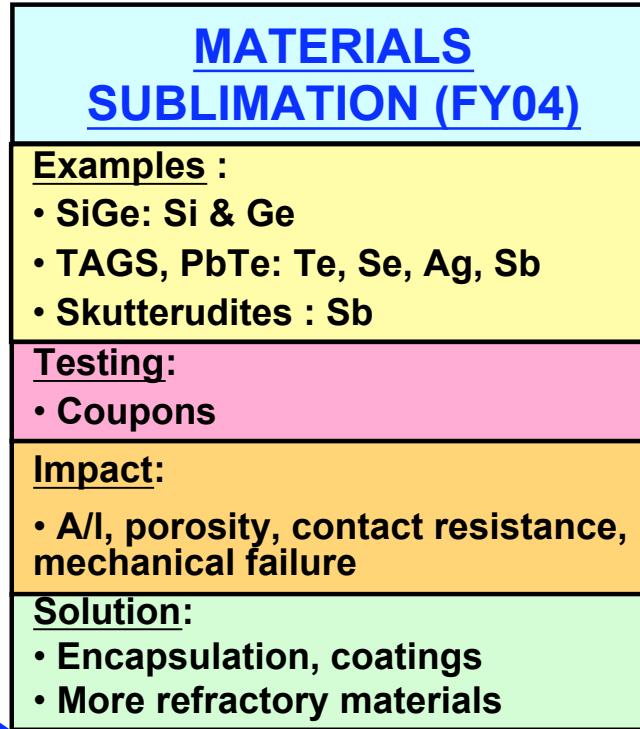
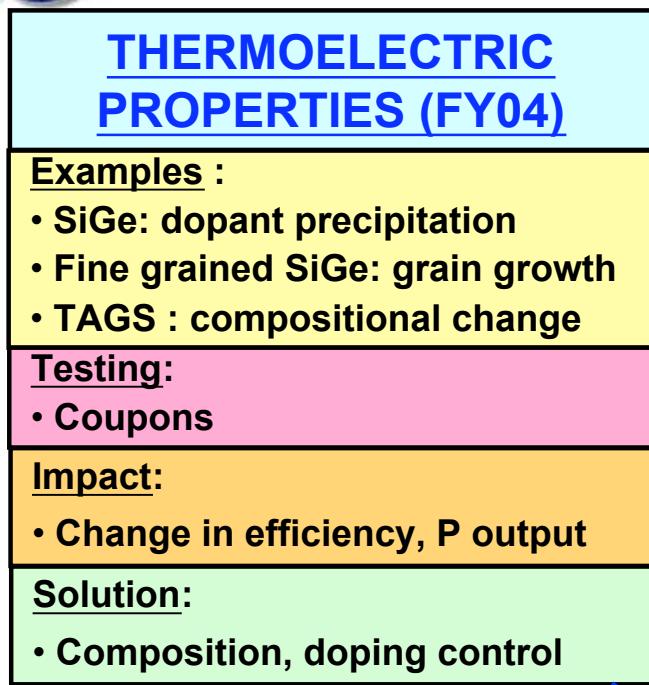


- Achieved ~14 % efficiency for 975K-300K ΔT
 - For fully segmented unicouple
- ➔ Translate into 12.5% efficiency for 975K-375K ΔT
- Fully validate projected efficiency performance

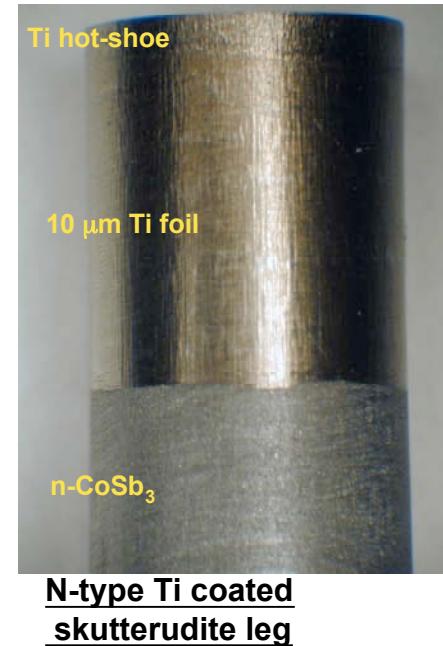
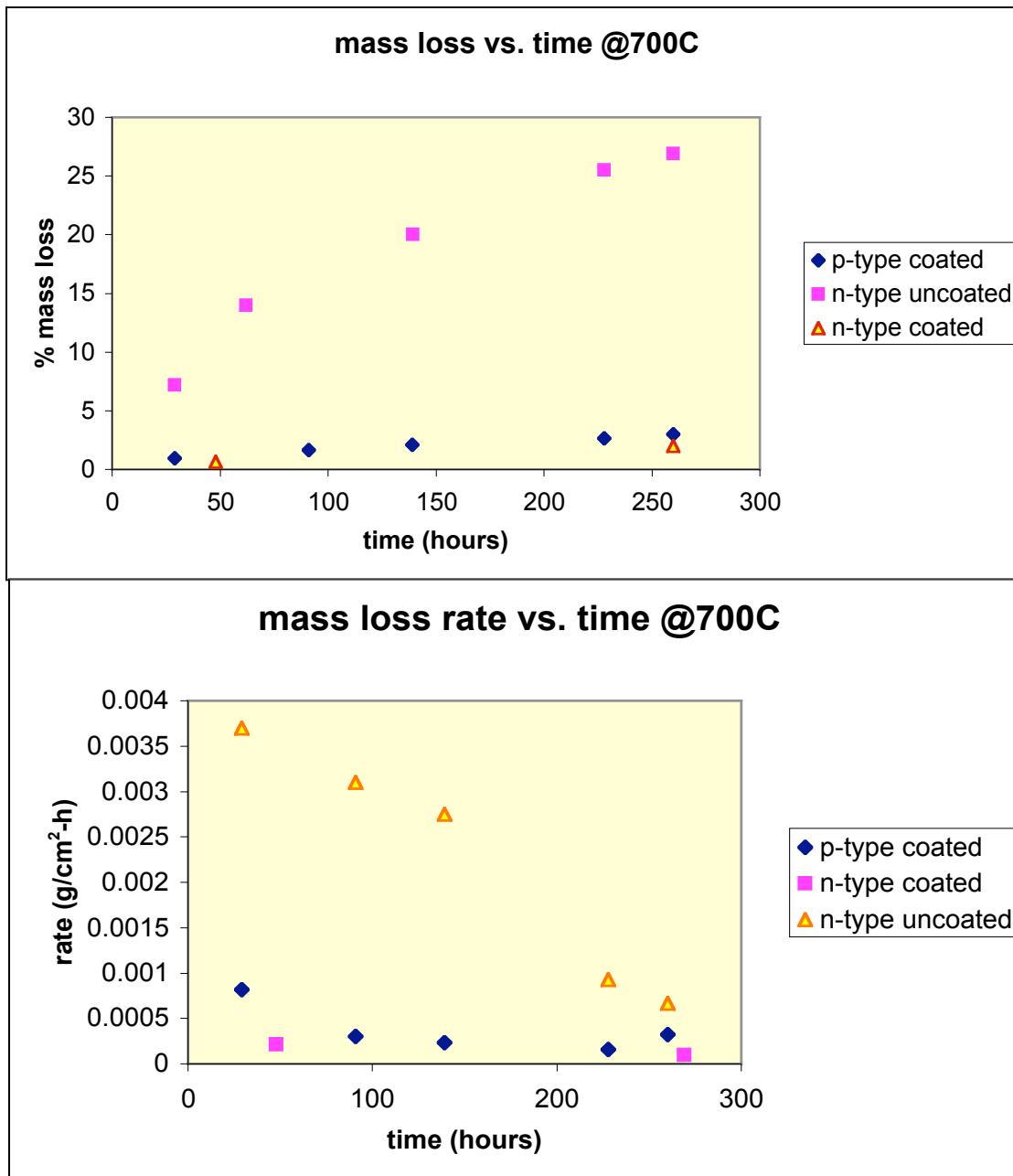




Lifetime performance testing and modeling development



Mass loss experiments results



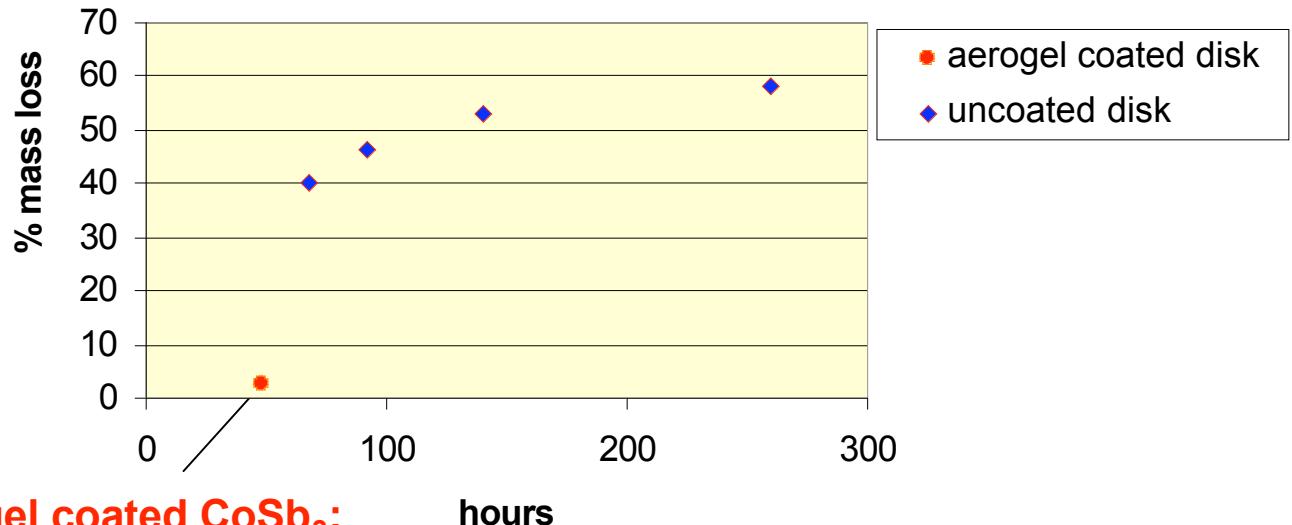
- Ti coating results in a significant mass loss reduction over uncoated



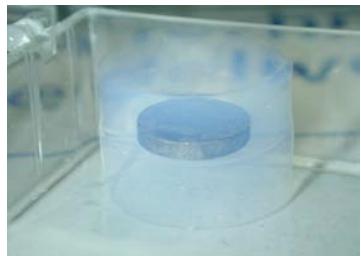
Aerogel encapsulated samples weight loss experiments

% mass loss vs. time for CoSb_3 disks

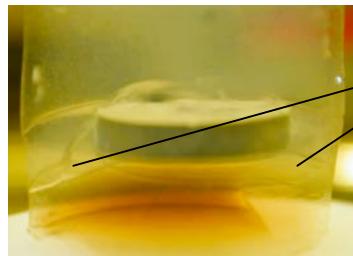
(700C 10^{-6} torr)



Aerogel coated CoSb_3 :
despite some cracks in
aerogel, no depletion
layer after 48h at 700C



before heating



after 48h at 700C

Cracks most likely result from aerogel shrinkage around disk: need to improve thermal stability and/or strength of aerogel



Back-up charts

Sublimation control experiments

- Isothermal anneal studies

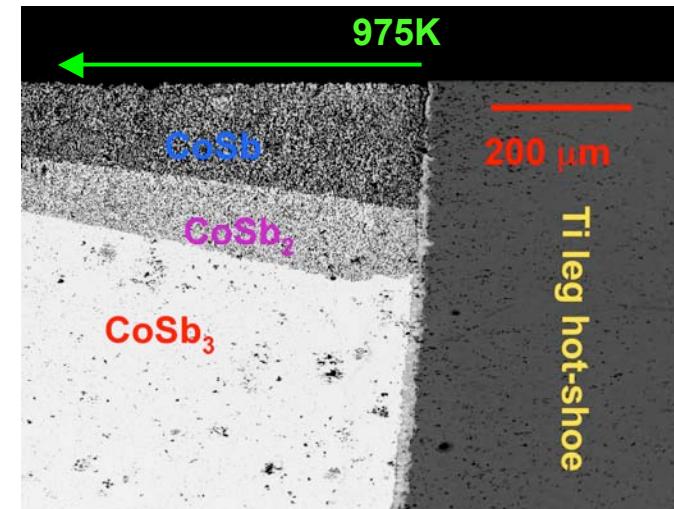
- Confirmed that n- and p-type skutterudites are phase stable at 700°C

- Uncoated samples

- Weight loss and temperature stability showed Sb sublimation in dynamic vacuum for T from ~ 875 to 975K for N-and p-type skutterudites
- Decomposition into lower antimonide compounds
- Appears to be diffusion limited

- Initial Sb sublimation control studies

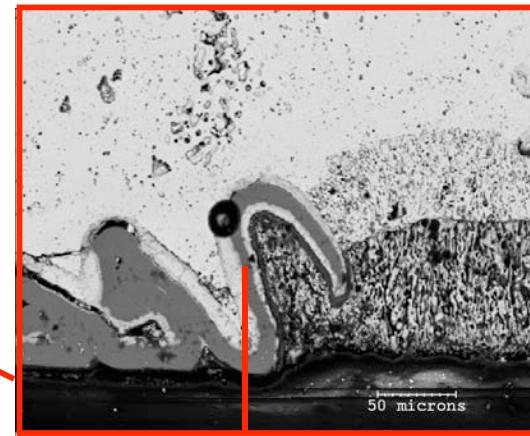
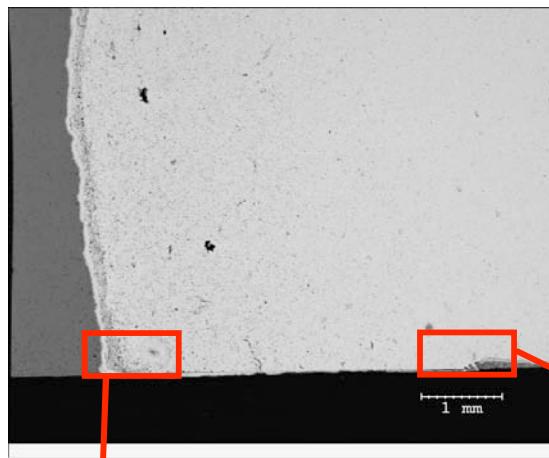
- Use of cover gas significantly suppresses Sb sublimation
- Thin metallic film applied during hot-pressing to the sample also significantly suppresses sublimation
- Thermal/mechanical modeling performed to evaluate impact on unicouple performance



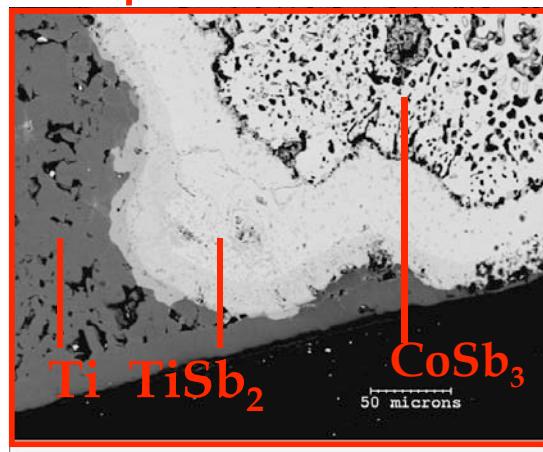
Photograph showing the decomposition of a CoSb₃ sample annealed in gradient for 3 months

Coated n-type tested in-gradient for 20 days

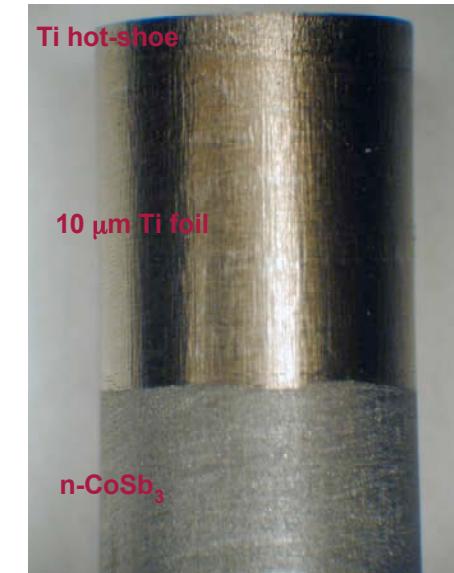
975K →



CoSb₃
CoSb₂
CoSb



Coating stops

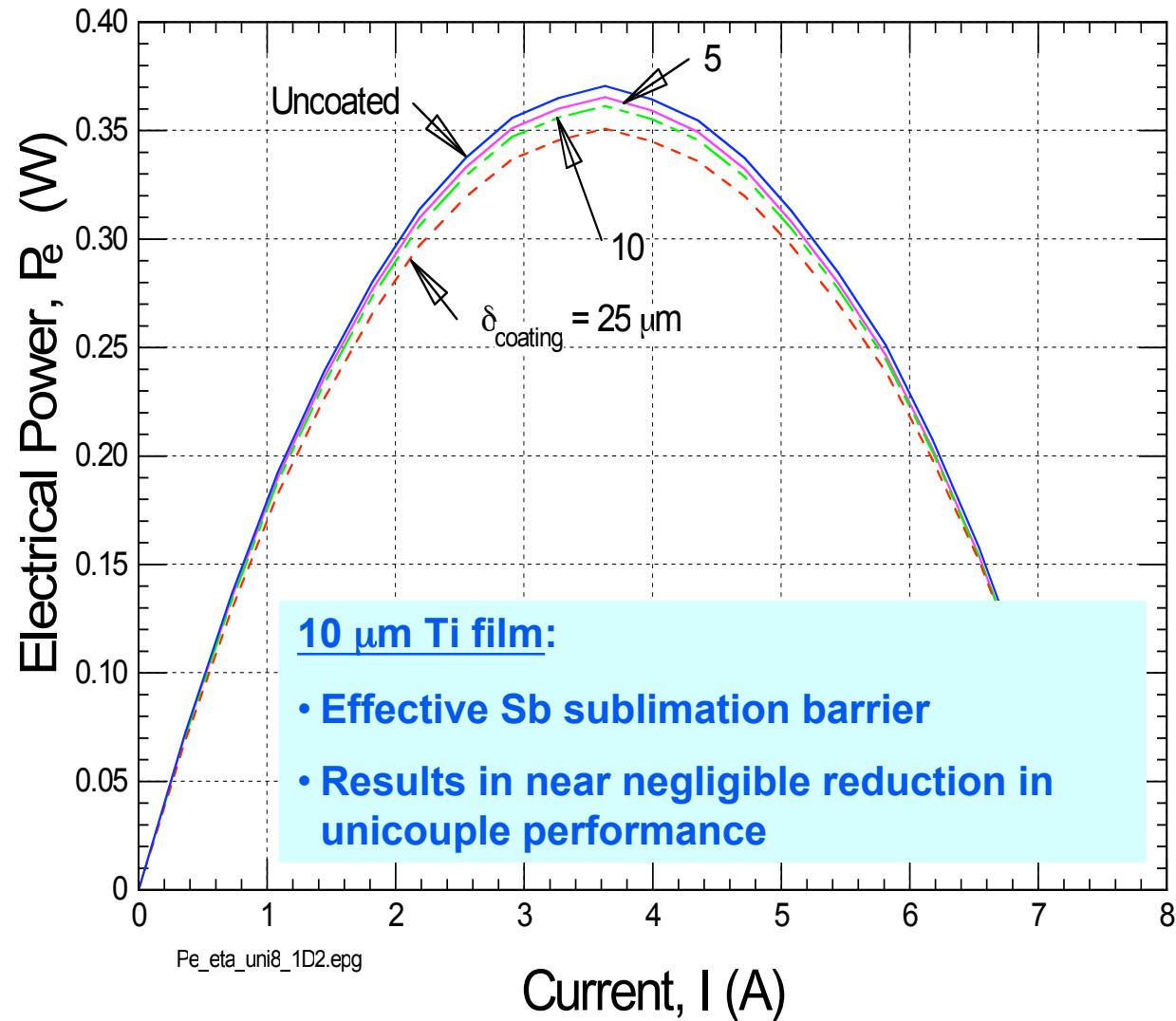
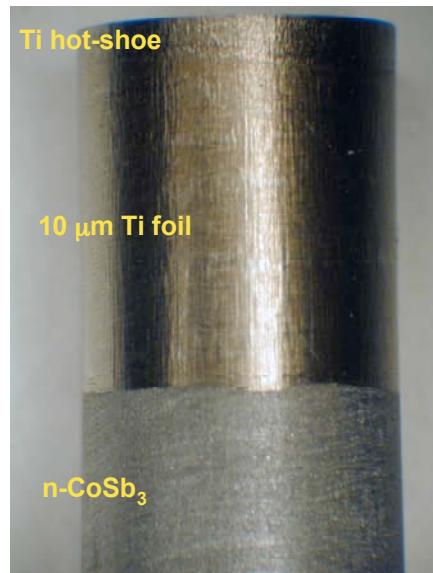
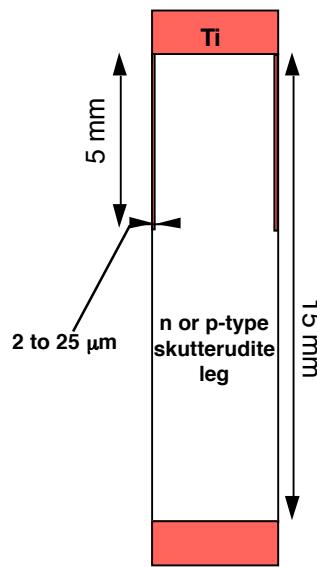


N-type Ti coated skutterudite leg

- No apparent degradation after 20 days
- Metal junction still intact
- Significant improvement over uncoated

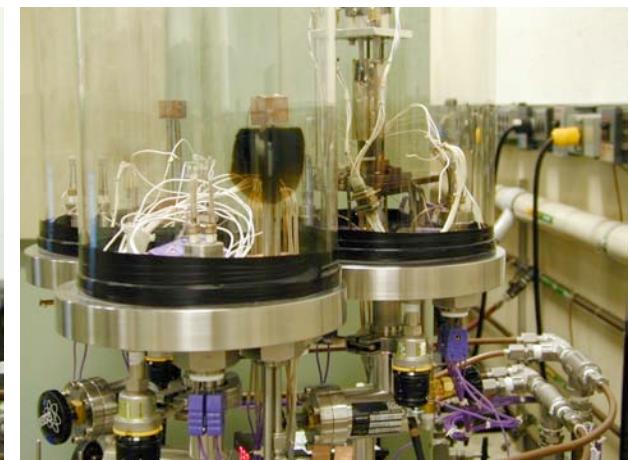
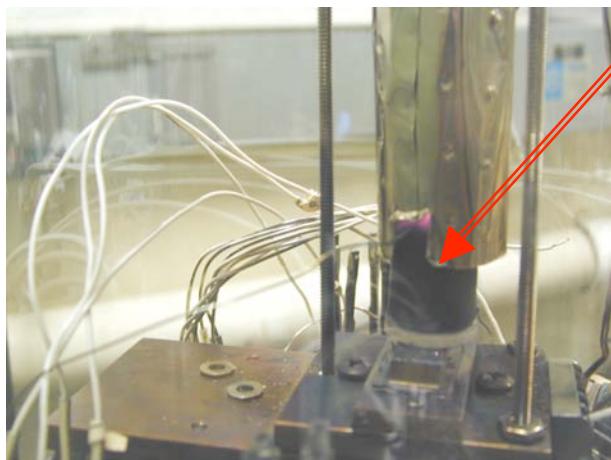
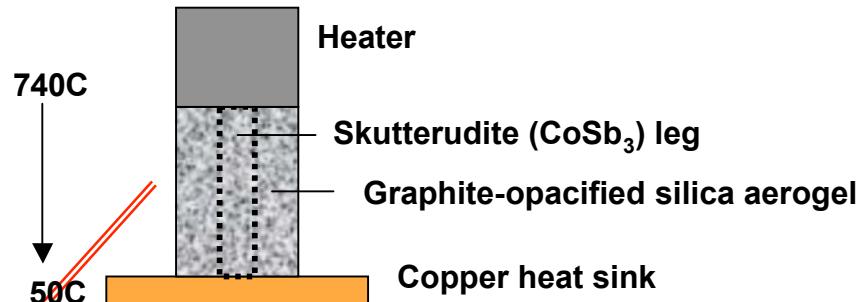


975K-375K Segmented TE Unicouple performance modeling (UNM)



Coating Material: Ti (length 5 mm and thickness = 0-25 μm)

Aerogel encapsulated skutterudite sublimation test



Skutterudite leg coated with graphite-opacified, silica aerogel. At 10·6 torr for 6 days. The absence of condensate on the inner-wall of the bell jar indicates that sublimation is completely suppressed.

Vacuum test station used to test sublimation coatings.

Condensation pattern of previous non-encapsulated sample sublimation test provides evidence of antimony sublimation.



Summary

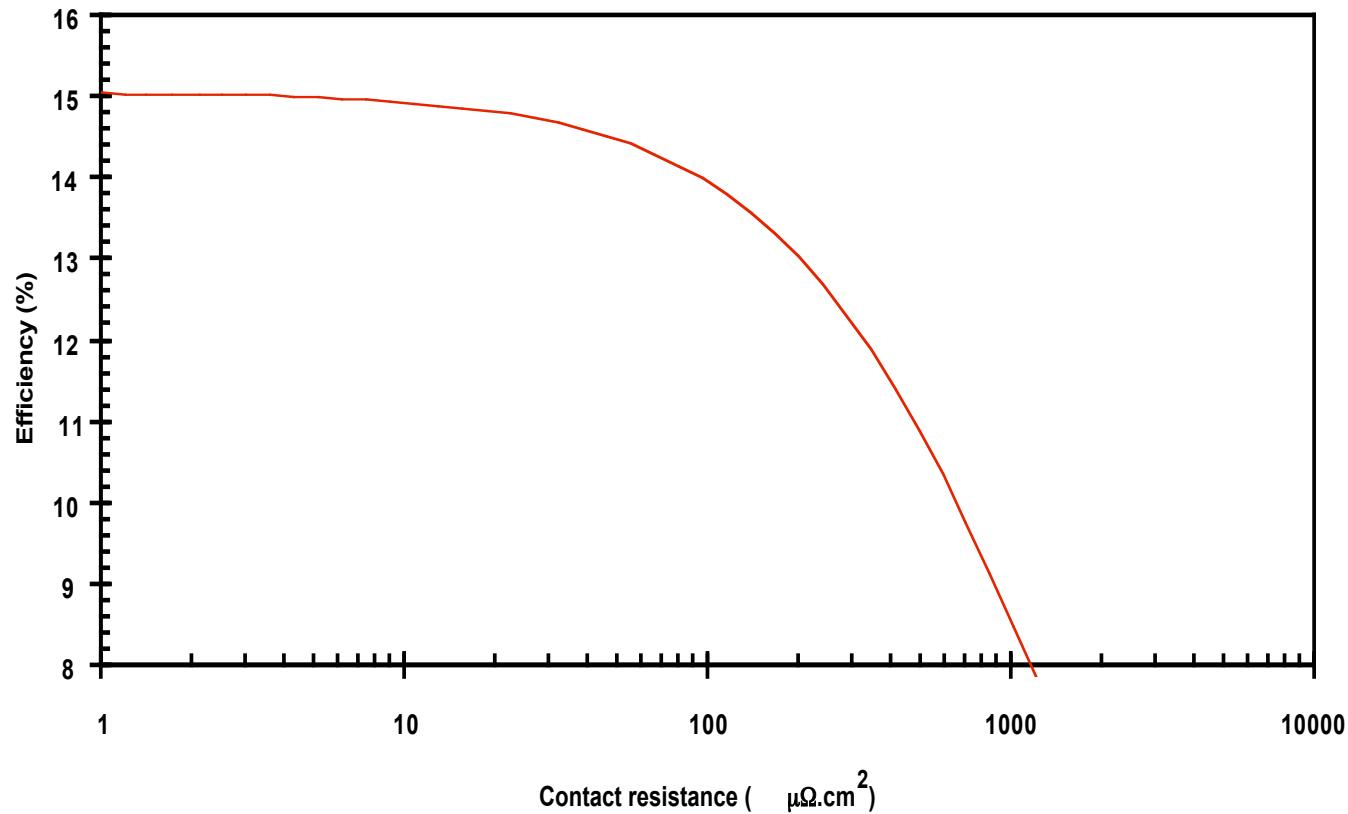


- Demonstrated ~ 14% efficiency for STE unicouples for 975K-300K ΔT
- Initiated life time studies

FY04-06 Major Focus Areas

- Optimize unicouple fabrication technique ; develop unicouple thermo-mechanical model
- Perform life testing of STE materials, coupons, components and unicouples
- Further develop sublimation control techniques/materials
- Develop lifetime model

Impact of electrical contact resistance on unicouple efficiency

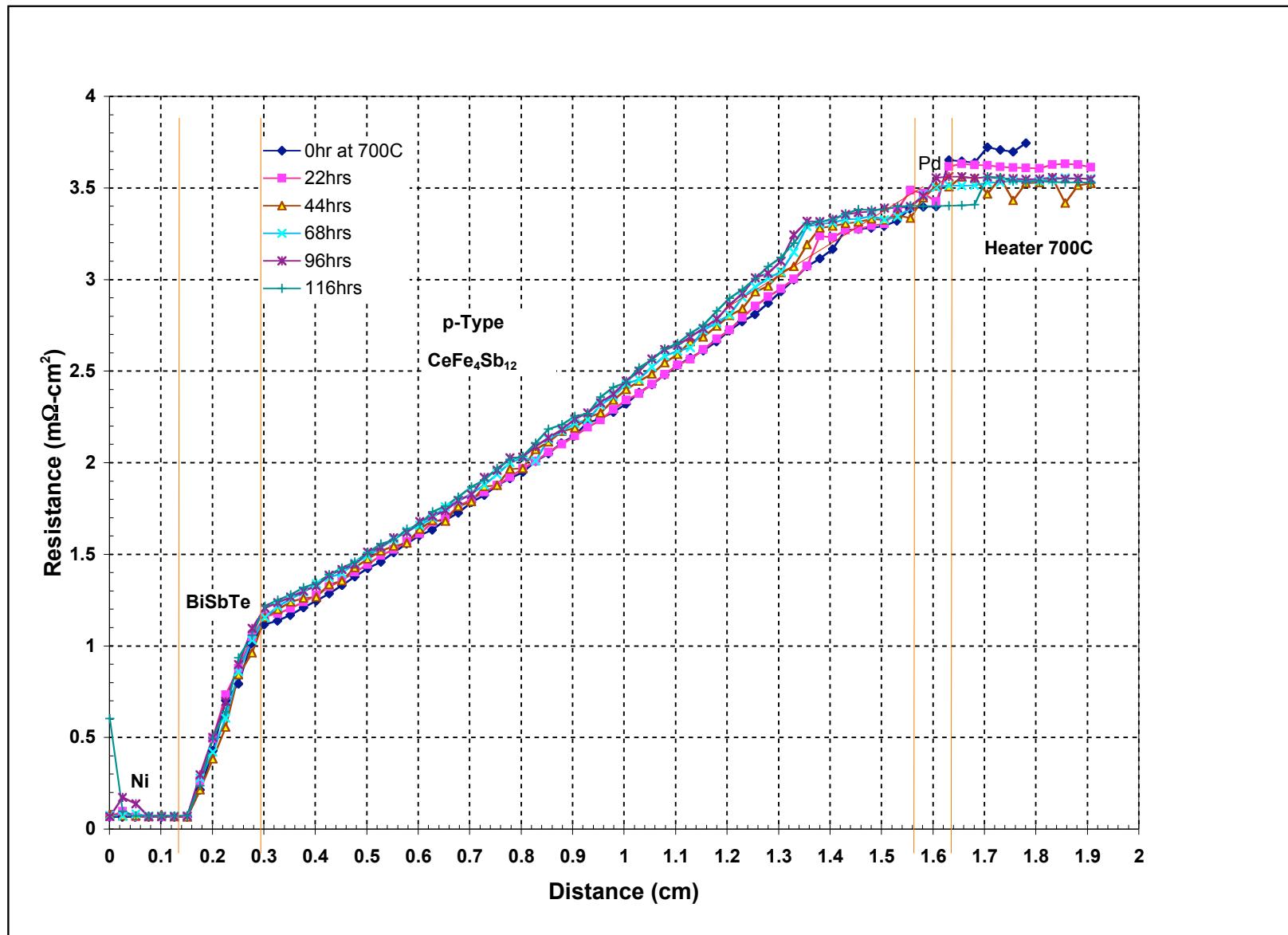


- Electrical contact resistance needs to be $< 5 \mu\Omega \cdot \text{cm}^2$ to prevent impact on converter efficiency



Electrical contact resistance measurements JPL

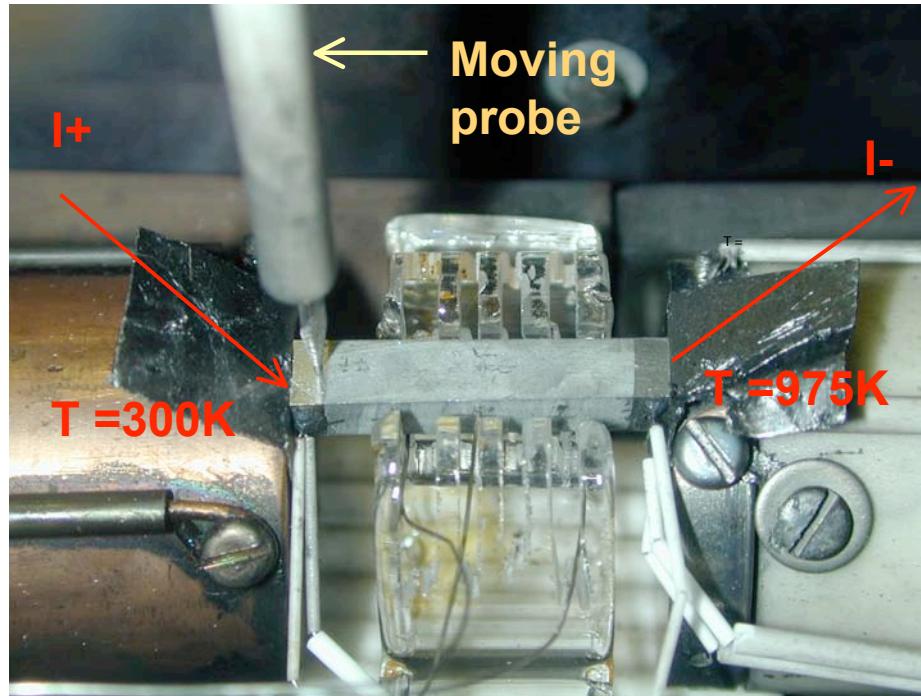
- Achieved electrical contact resistance $< 5 \mu\Omega\text{cm}^2$ at the segmented legs interfaces



Segmented legs electrical contact

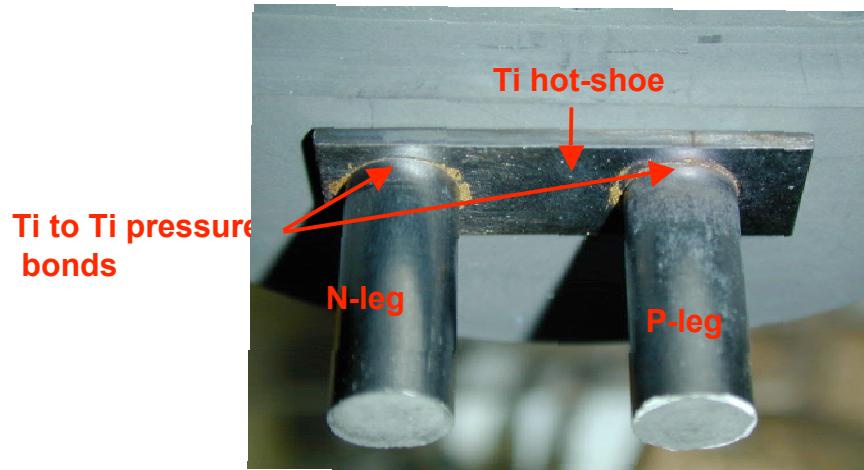
resistance measurements

- Bond quality
 - Electrical contact resistance measurement
 - Microprobe analysis
 - Diffusion
 - Chemical reaction and interface layer analysis



Electrical contact resistance measurements set-up

Unicouple fabrication process developed



Unicouple fabricated by hot-pressing

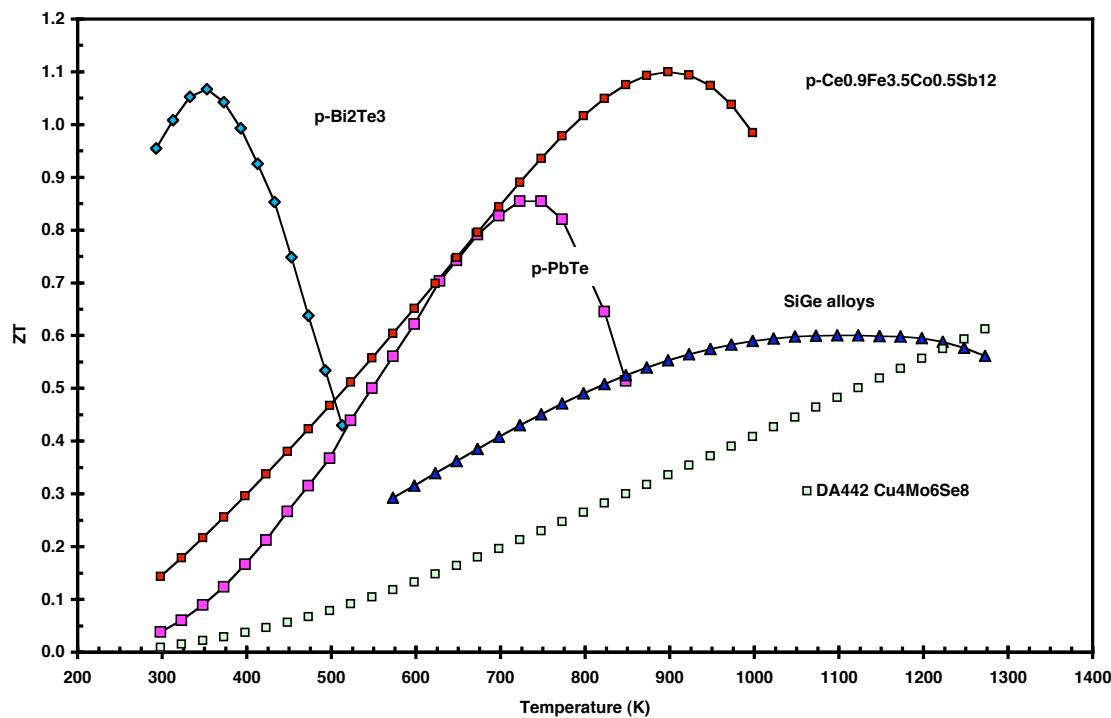


Graphite die used for unicouple fabrication

- Developed a process to fabricate unicouple by hot-pressing
 - P- and n-leg alternatively hot-pressed onto a Ti hot-shoe
 - No measurable electrical contact resistance between TE legs and Ti hot-shoe
 - Requires further optimization but very promising
- Process compatible with batch manufacturing

High Temperature Materials

- **Chevrel chalcogenides (Mo_6Se_8 -based)**
 - Synthesized several additional Cu and Fe filled Mo_6Se_8 compositions using a powder metallurgy technique
 - Measured Seebeck coefficient, electrical resistivity, and thermal conductivity from 300K to 1275K
 - Achieved $ZT \sim 0.6$ at 1275K for $\text{Cu}_4\text{Mo}_6\text{Se}_8$ composition, comparable to SiGe
 - Tested $\text{Cu}_4\text{Mo}_6\text{Se}_8$ sample under electrical load (potential Cu electromigration)
 - Sample shows no indication of electromigration after 6 days at 900°C under 5A load current



Cu₄Mo₆Se₈ sample tested for 6 days at 900C under 5A load